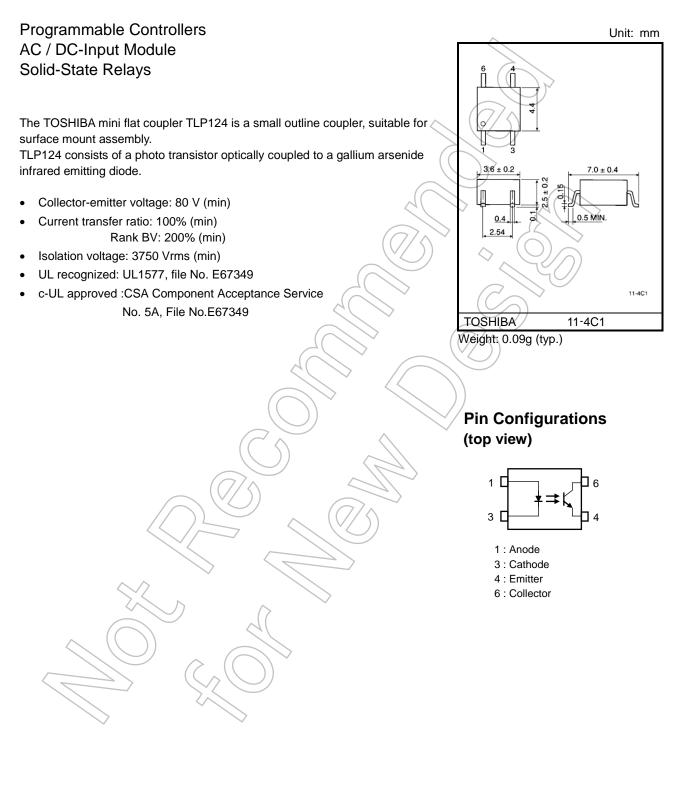
TOSHIBA Photocoupler GaAs Ired & Photo-Transistor

TLP124



Start of commercial production 1988-04

Current Transfer Ratio

	Cu			
Classification	Ta =	25°C	Ta = -25 to 75°C	Marking of
(Note 1)	IF = 1 mA VCE = 0.5 V	IF = 0.5 mA VCE = 1.5 V	IF = 1 mA VCE = 0.5 V	Classification
Rank BV	200%	100%	100%	BV
Standard	100%	50%	50%	BV, Blank

Note 1: Ex, rank BV: TLP124(BV)

Note: Application type name for certification test, please use standard product type name, i, e. TLP124(BV): TLP124

Absolute Maximum Ratings (Ta = 25°C)

	5 (,			-
	Characteristic	Symbol	Rating	Unit	
	Forward current	lF	50	mA	$\mathcal{A}(\mathbb{N})$
	Forward current derating (Ta ≥ 53°C)	ΔIF/°C	-0/7	mA/°C	5
LED	Peak forward current (100 µs pulse, 100 pps)	IFP		A	≤ 0
Ш	Reverse voltage	Vr <	5	(\mathcal{Y})	*
	Diode power dissipation	PD	100	mW	
	Diode power dissipation derating $(Ta \ge 53^{\circ}C)$	ΔP _D /°C	-1.39	mW/°C	
	Junction temperature	Tj	125	°C	
	Collector-emitter voltage	VCEO	80	V	
	Emitter-collector voltage	VECO	7	V	
	Collector current	lc	50	mA	
Detector	Peak collector current (10 ms pulse, 100 pps)		100	mA	
De	Power dissipation	Pc	150	mW	
	Power dissipation derating (Ta ≥ 25°C)	ΔPc/°C	-1.5	mW/°C	
	Junction temperature		125	°C	
Stor	rage temperature range	T _{stg}	-55 to 125	°C	
Оре	erating temperature range	Topr	-55 to 100	°C	
Lea	d soldering temperature (10 s)	T _{sol}	260	°C	
Tota	al package power dissipation	Рт	200	mW	
	al package power dissipation $(Ta \ge 25^{\circ}C)$	ΔP _T /°C	-2.0	mW/°C	
Isol (AC	ation voltage , 60 s, R.H. ≤ 60%) (Note 1)	BVS	3750	Vrms	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

Note 1: Device considered a two terminal device: Pins1, 3 shorted together and pins 4, 6 shorted together.

Recommended Operating Conditions

Characteristic	Symbol	Min	Тур.	Max	Unit
Supply voltage	Vcc	_	5	48	V
Forward current	lF	_	1.6	20	mA
Collector current	IC	_	1	10	mA
Operating temperature	Topr	-25	-	75	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Electrical Characteristics (Ta = 25°C)

	Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward voltage	VF	IF = 10 mA	1.0	1.15	1.3	V
LED	Reverse Current	I _R	$V_R = 5 V$	(($D \rightarrow C$	10	μΑ
	Capacitance	Ст	V = 0 V, f = 1 MHz	À	30	/ _	pF
	Collector-emitter breakdown voltage	V _{(BR)CEO}	Ic = 0.5 mA	80		-	V
or	Emitter-collector breakdown voltage	V _{(BR)ECO}	IE = 0.1 mA	7)	—	-	V
etect	Collector dark current	ICEO	VCE = 48 V		10	100	nA
ð			Vce = 48 V, Ta = 85°C) —	2	50	μΑ
	Capacitance collector to emitter	CCE	V = 0 V, f = 1 MHz	_	12	_	pF

Coupled Electrical Characteristics ($Ta = 25^{\circ}C$)

Characteristic	Symbol	Test Condition		Min	Тур.	Max	Unit
Current transfer ratio	IC/IF	I _F = 1 mA, V _{CE} = 0.5 V		100	_	1200	%
			Rank BV	200	—	1200	70
Low input CTR		IF = 0.5 mA, VCE = 1.5 V		50			%
	IC/IF(low)		Rank BV	100	_	_	70
		Ic = 0.5 mA, I _F = 1 mA		_	_	0.4	
Collector-emitter saturation voltage	VCE(sat)	Ic = 1 mA, I _F = 1 mA		_	0.2	_	V
2/	\wedge	\sim	Rank BV	_	_	0.4	
Off-state collector current	C(off)	$V_F = 0.7 V, V_{CE} = 48 V$		_	_	10	μA

Coupled Electrical Characteristics (Ta = -25 to 75°C)

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Current transfer ratio		IF = 1 mA, VCE = 0.5 V	50	_	—	%
Current transfer fatio	IC/IF	Rank BV	100	_	—	%
Low input CTR		I _F = 0.5 mA, V _{CE} = 1.5 V	_	50	_	%
	IC/IF(low)	Rank BV	_	100	_	%

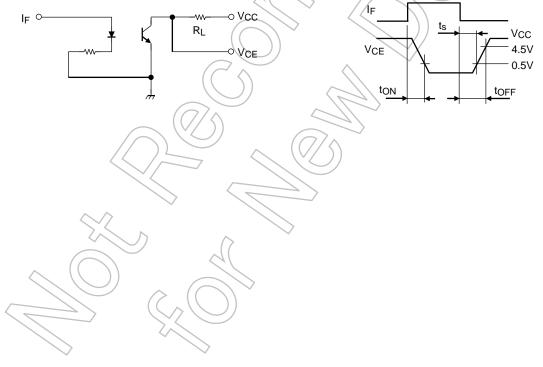
Isolation Characteristics (Ta = 25°C)

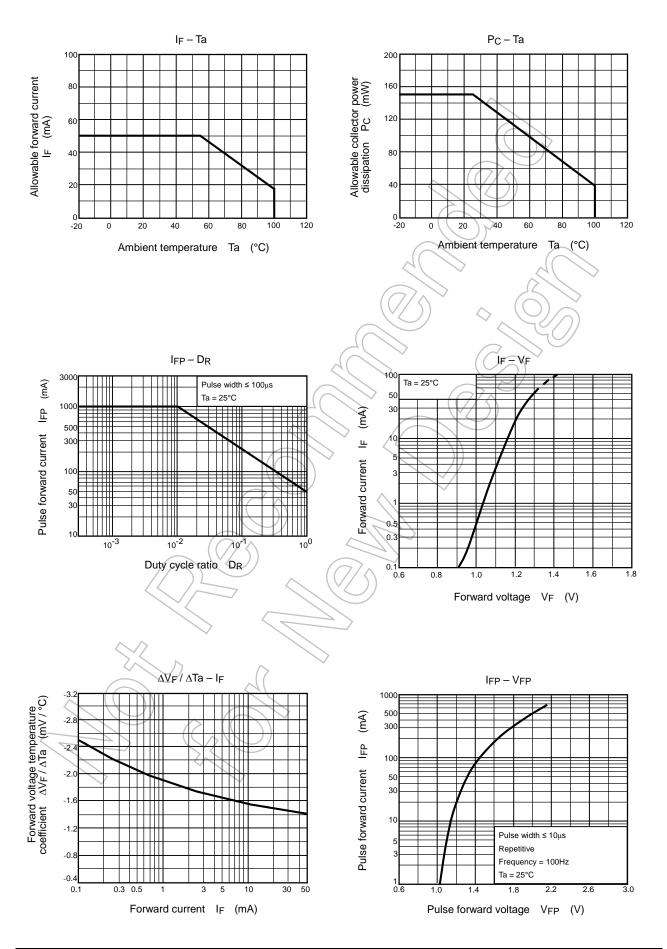
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance (input to output)	CS	V _S = 0 V, f = 1 MHz	_	0.8	_	pF
Isolation resistance	Rs	Vs = 500 V, R.H. ≤ 60%	5×10 ¹⁰	10 ¹⁴		Ω
Isolation voltage	BVS	AC, 60 s	3750	-		
		AC, 1 s, in oil	(-)	10000		Vrms
		DC, 60 s, in oil		10000		V _{dc}

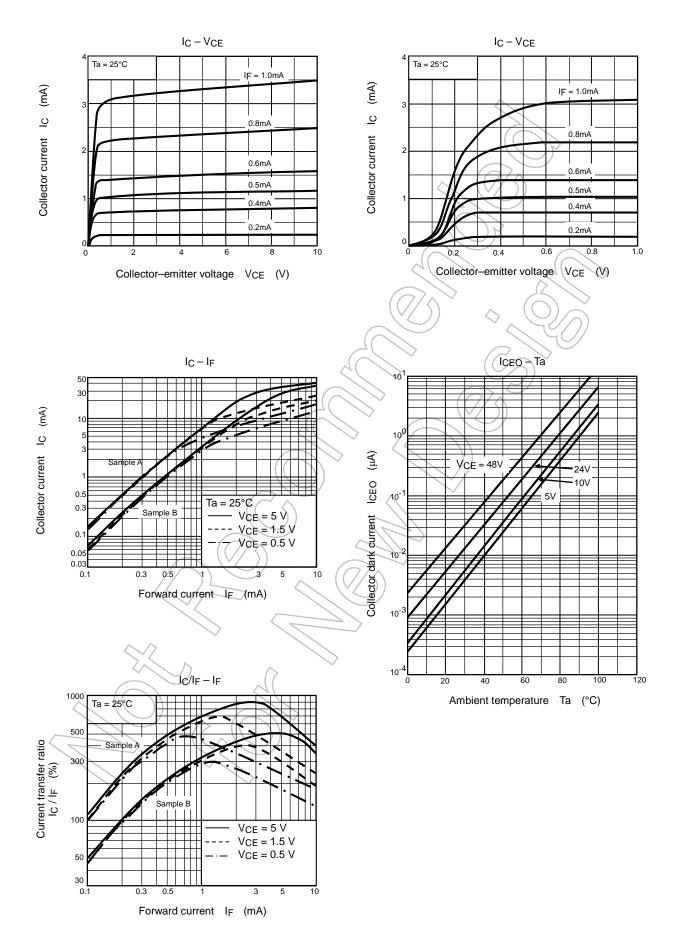
Switching Characteristics (Ta = 25°C)

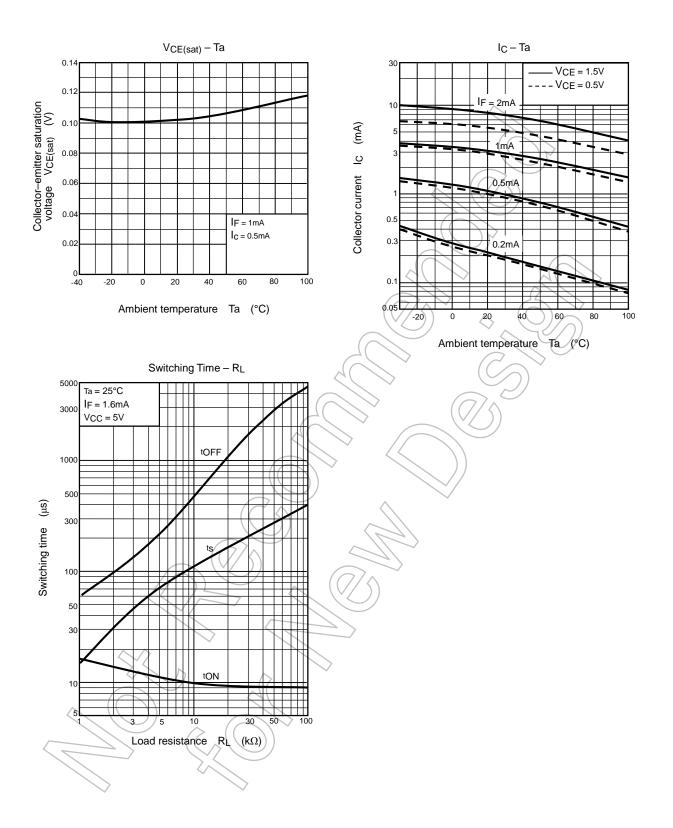
Characteristic	Symbol	Test Condition Min Typ. Max Unit
Rise time	tr	
Fall time	t _f	$V_{CC} = 10 V, I_C = 2 mA$ – 8 –
Turn-on time	ton	RL = 100 Ω μs
Turn-off time	tOFF	
Turn-on time	ton	- 10 -
Storage time	ts	$R_L = 4.7 k\Omega$ (Fig.1) — 50 — μs
Turn-off time	tOFF	- 300 -

Fig. 1 Switching time test circuit









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